

Modifications to K-P Displacement Model & Stopping Powers

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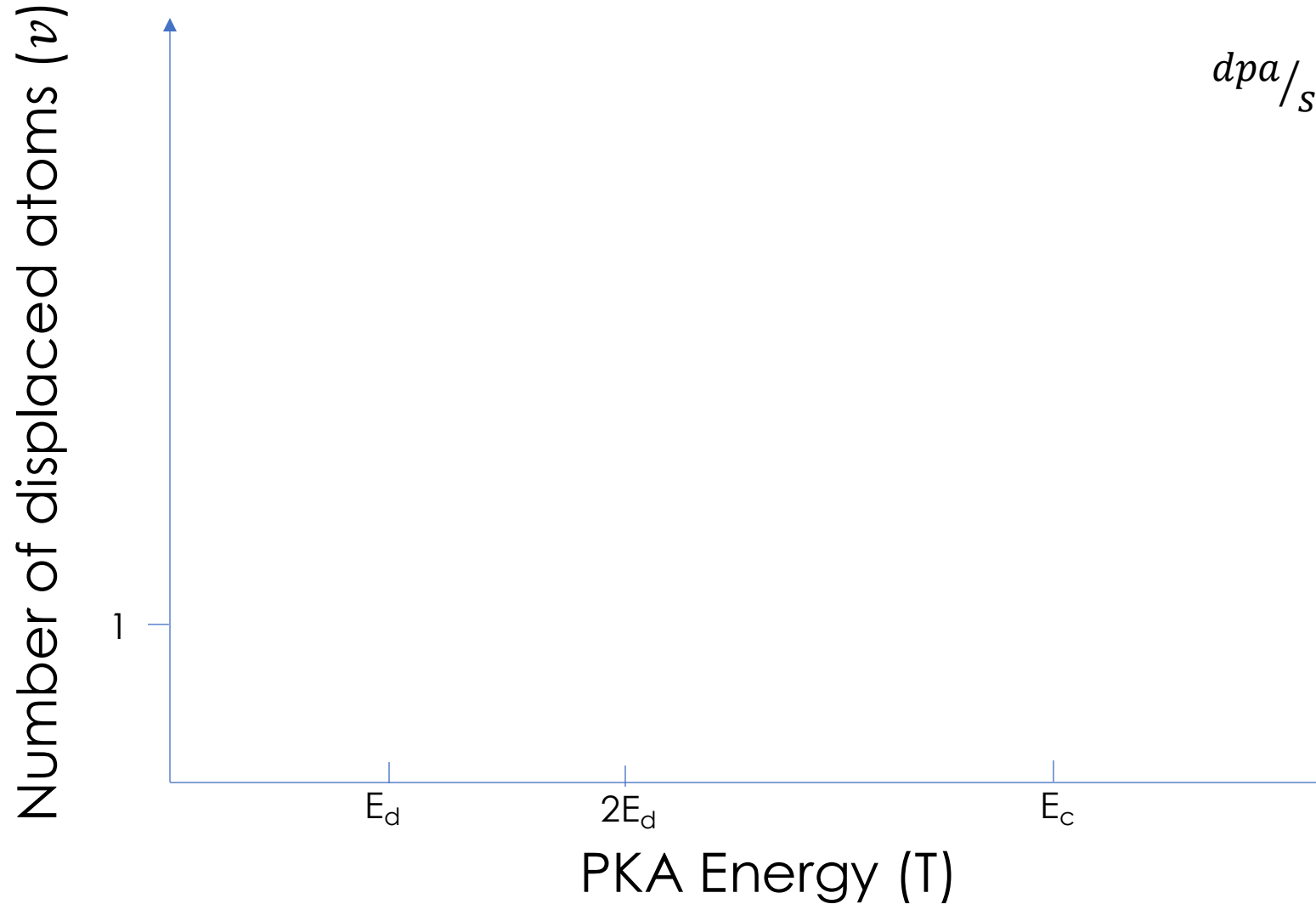
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Summary of Topics Covered



$$dpa/s = N \int_{\check{E}}^{\hat{E}} \Phi(E_i) \int_{\check{T}}^{\hat{T}} \sigma(E_i, T) v(T) dT dE_i$$

Brain storming

- Why would the K-P model not be correct? (but reasonable)

Outline

Stopping Powers:

- Remember E_c
- Concept of stopping power
- Regimes of electronic energy loss
- Compare electronic and nuclear stopping

Modifications of K-P Model:

- Accounting for electronic energy loss
- Effects of crystallinity
- NRT model + Arc-dpa model

Goal: Understand the concept of stopping power and how different physics modifies the displacement model



A simple picture of slowing down

- The slowing down process of an ion impacting on a surface:

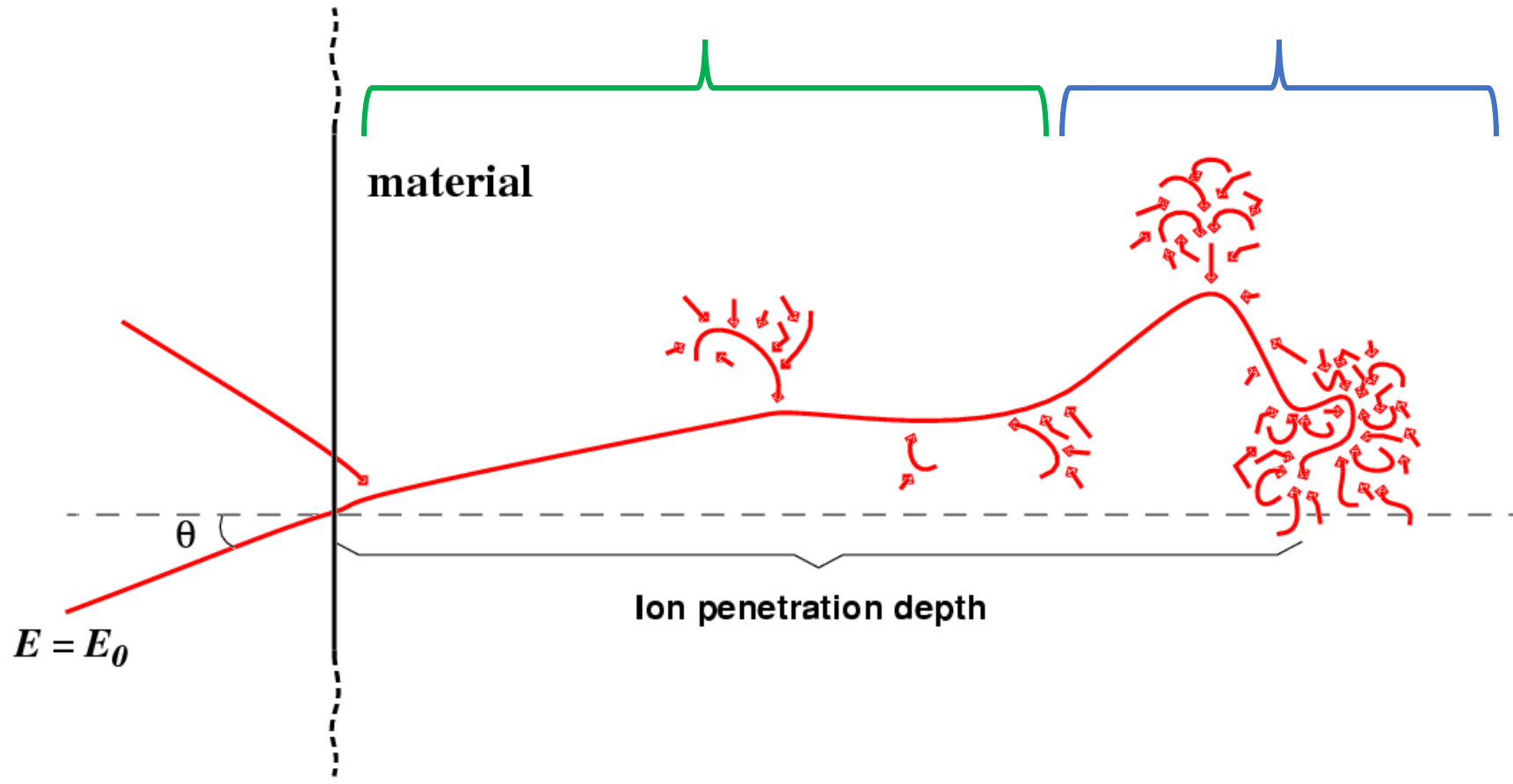
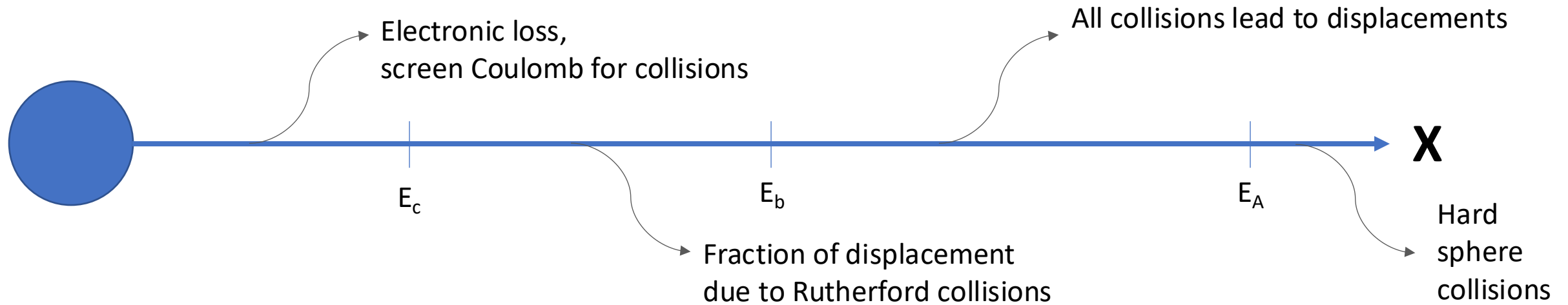


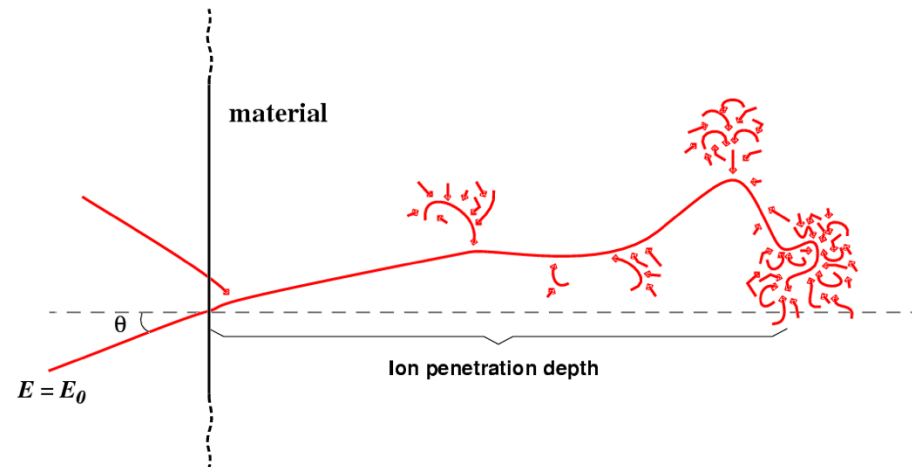
Image: Kai Nordlud

Regimes of energy loss of a PKA



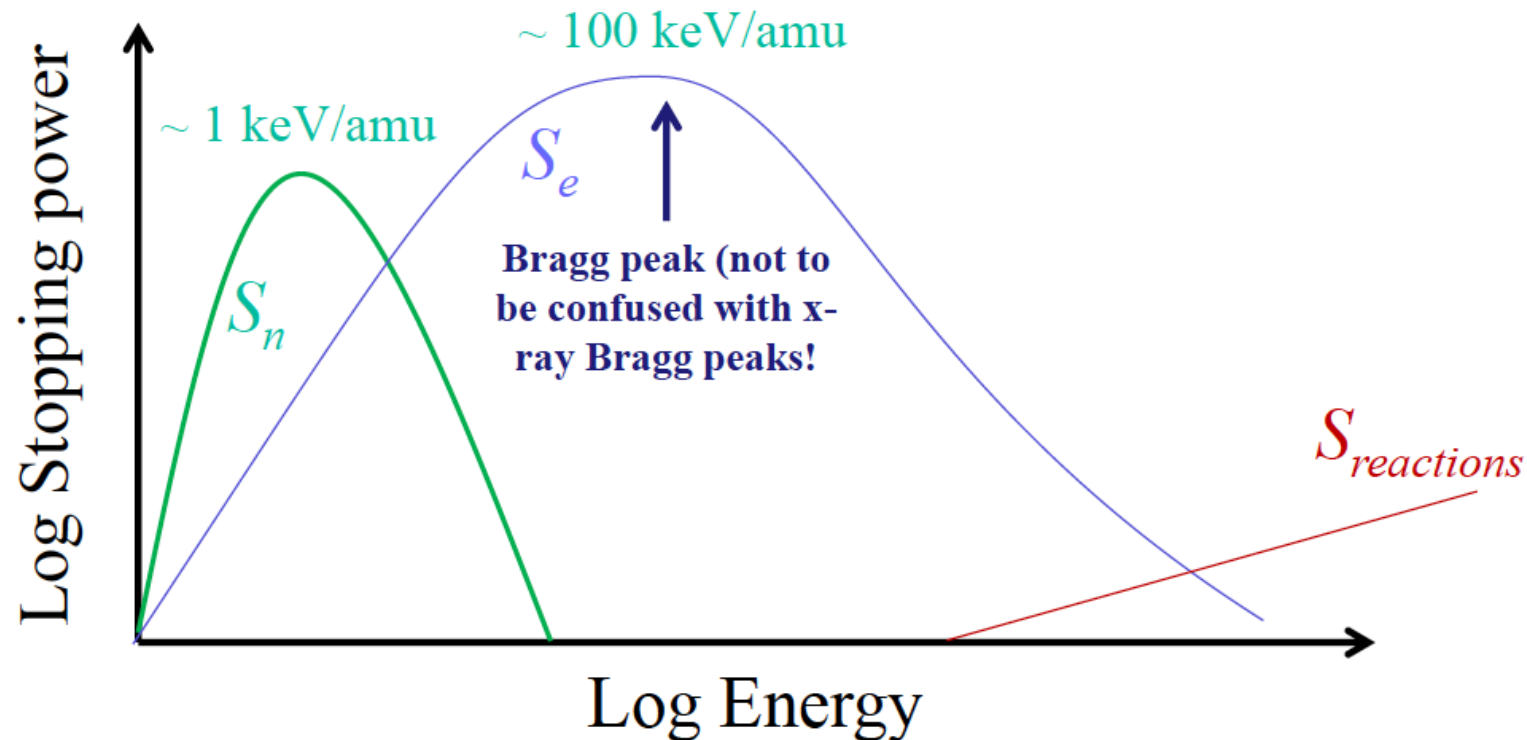
The concept of stopping power

- Since the electronic collisions only slow down the ion, the effect of the electrons can be considered to be an average frictional force slowing down the ion
 - This is known as the **electronic stopping power**
- The collisions with ions can also be averaged and then considered a **nuclear stopping power**
- The nuclear reactions can also be averaged and considered a **nuclear reaction stopping power**



Stopping power

- The total stopping power can be written as
- Schematically, the energy dependence of these is then:



Stopping power

- The total stopping power can be written as

Terminology Notes:

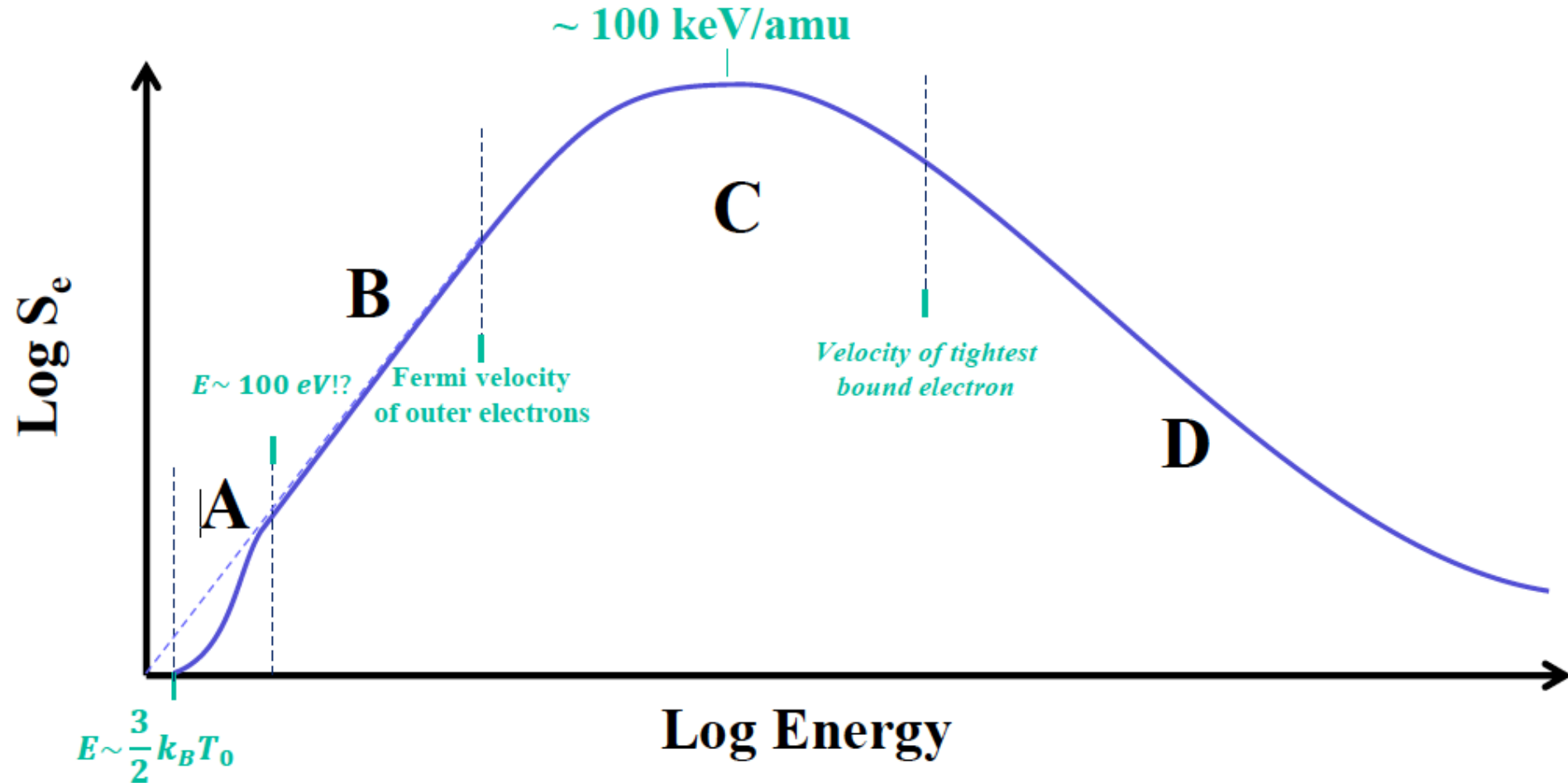
- Sche
 - In detector and space physics different terms are used:
 - Linear Energy Transfer (LET) is used for total or **electronic stopping power**
 - Total and electronic are about the same in this field due to the high energies (MeV and GeV)
 - Non-ionizing energy loss is used for **nuclear stopping power**

Log Energy



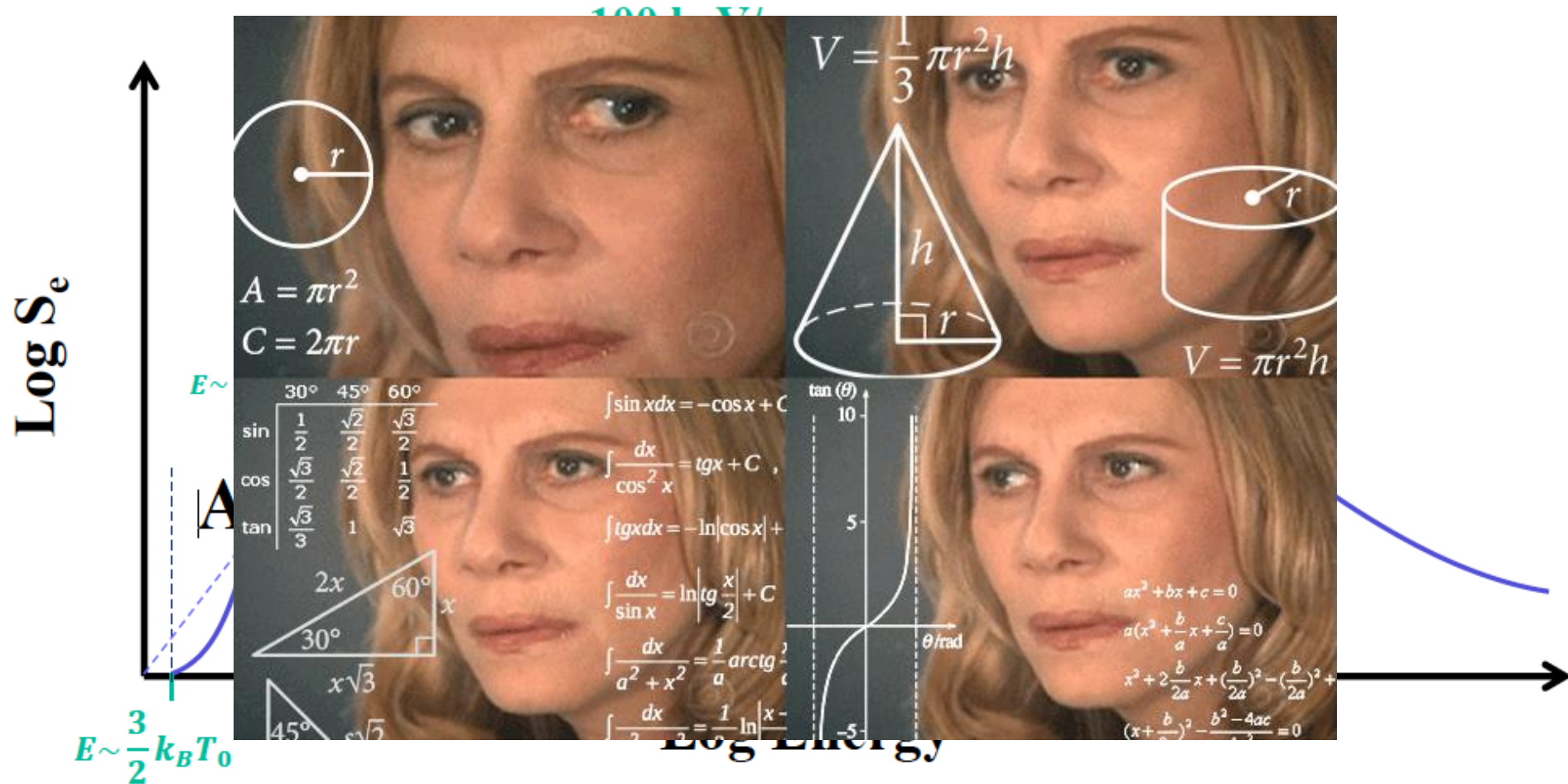
Regimes of electronic stopping power

- Electronic stopping can be segregated into four primary regimes:



Regimes of electronic stopping power

- Electronic stopping can be segregated into four primary regimes:



Stopping powers

- $(-dE/dx)_{total}$ can be written in terms of stopping power (units of energy * distance²):

$$\left(-\frac{dE}{dx}\right)_{total} = NS_n + NS_e$$

- Nuclear:

$$\left(-\frac{dE}{dx}\right)_n = \frac{N\pi Z_1 Z_2 \varepsilon^4}{E_i} \frac{M_1}{M_2} \ln \left(\frac{\gamma E_i}{\frac{\varepsilon^2 \gamma E_a^2}{4E_i}} \right)$$

- Electronic:

$$\left(-\frac{dE}{dx}\right)_e = \frac{N2\pi Z_1^2 Z_2 \varepsilon^4}{E_i} \frac{M}{m_e} \ln \left(\frac{\gamma_e E_i}{\bar{I}} \right) = \frac{2\pi N Z_1^2 M \varepsilon^4}{m_e E_i} B \quad B = Z_2 \ln \left(\frac{\gamma_e E_i}{\bar{I}} \right)$$



Relative Stopping Powers

- Compare S_e/S_n :

- Electronic stopping power dominates for high energy ions

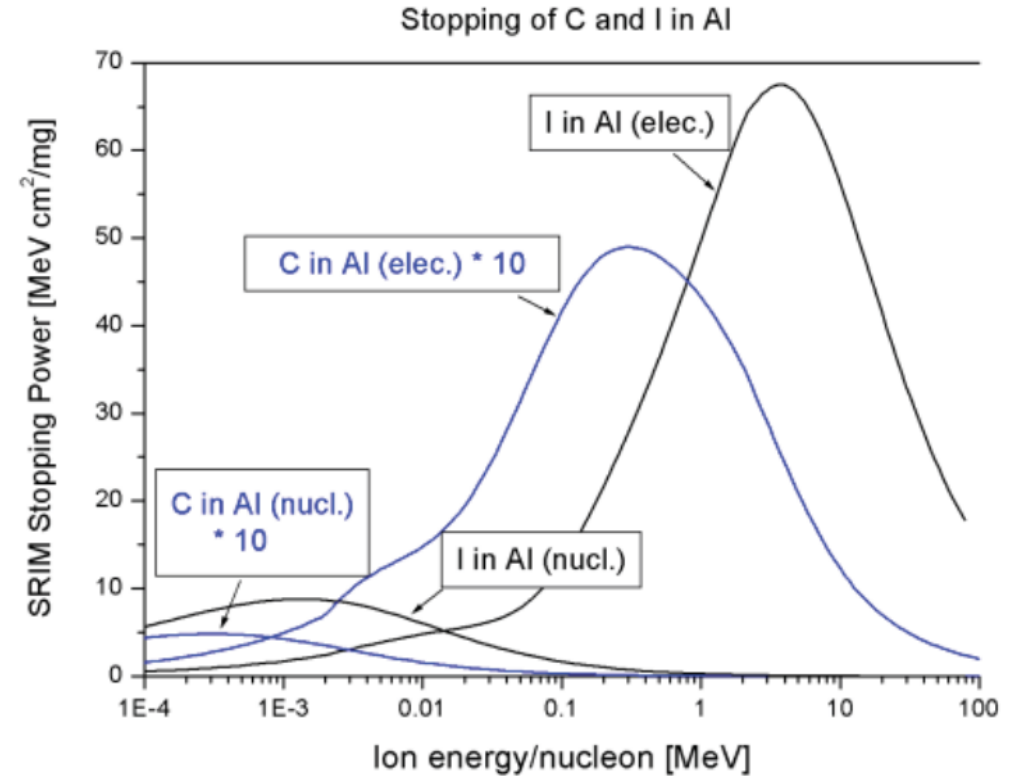


FIGURE 2. Electronic and nuclear mass stopping power for carbon and iodine ions in aluminum, calculated using SRIM.

Stopping powers

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Table 1.7 Summary of energy loss rates for various types of interactions

Type of interaction	Nuclear energy loss rate $\left(-\frac{dE}{dx}\right)_n$		Electronic energy loss rate $\left(-\frac{dE}{dx}\right)_e$	
<i>High E</i> Coulomb	$\frac{4N\pi Z^4 a_0^2 E_R^2}{E_i} \ln\left(\frac{a^2 c^2 E_i^2}{4a_0^2 E_R^2 Z^4}\right)$	(1.134)	$N\pi \frac{Z_1^2 Z_2 \varepsilon^4}{E_i} \frac{M}{m_e} \ln\left(\frac{\gamma_e E_i}{\bar{I}}\right)$	(1.173)
<i>Low E</i>	General expression: $\frac{8.462 \times 10^{-15} N Z_1 Z_2 M_1 S_n(\epsilon)}{(M_1 + M_2)(Z_1^{0.23} + Z_2^{0.23})}$	(1.169)	$k' E_i^{1/2}$	(1.178)
			$k' = 3.83 \frac{Z_1^{7/6} Z_2}{M_1^{1/2} (Z_1^{2/3} + Z_2^{2/3})^{3/2}}$	(1.179)
	Inverse square: $\frac{\pi^2}{4} a^2 N E_a \gamma$	(1.159)	$k E_i^{1/2}$	(1.190)
	Thomas–Fermi screening: $K \frac{N Z_1 Z_2}{Z^{1/3}} \frac{M_1}{M_1 + M_2}$ where $Z^{1/3} = (Z_1^{2/3} + Z_2^{2/3})^{1/2}$ and $K = \left(\frac{\pi}{e}\right) \varepsilon^2 a_0 = 2.8 \times 10^{-15} \text{ eV} \cdot \text{cm}^2$	(1.163)	$k = 8\sigma_e N \left(\frac{m_e}{M_1}\right)^{1/2}$ valid for $0 < E \text{ (keV)} < 37Z^{7/3}$	

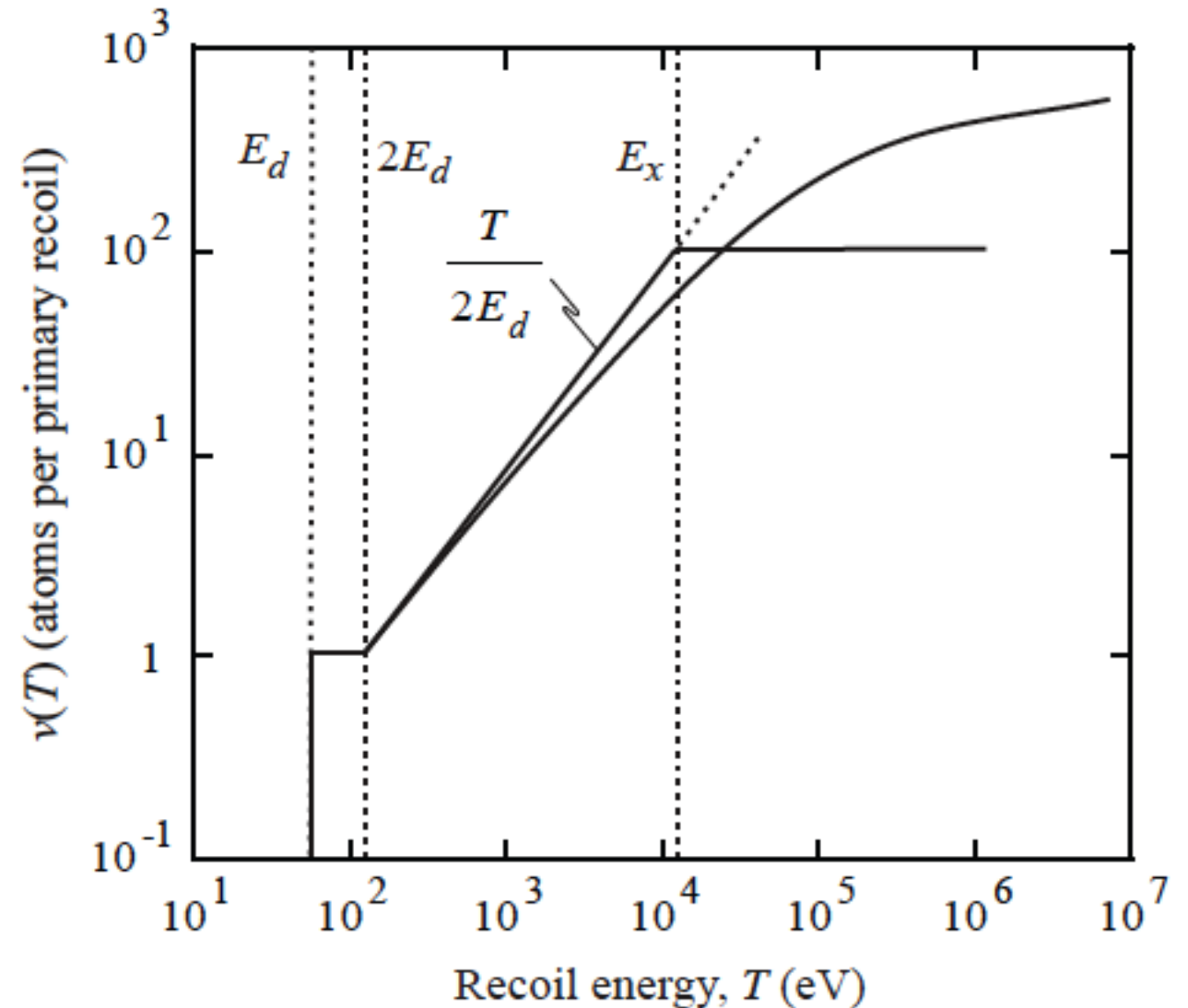
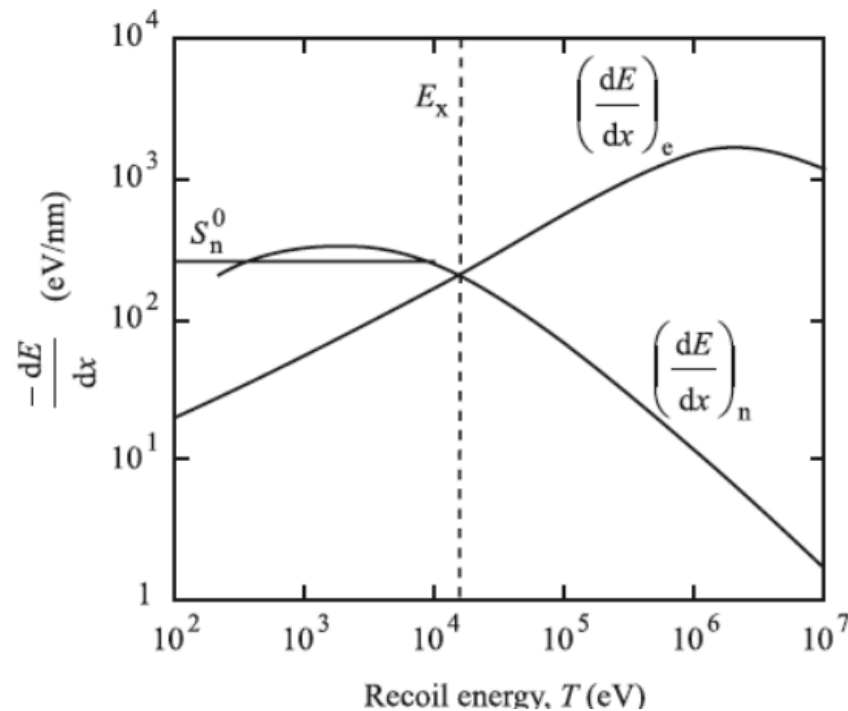




Modifications to K-P Model

1. Correction for electron energy loss

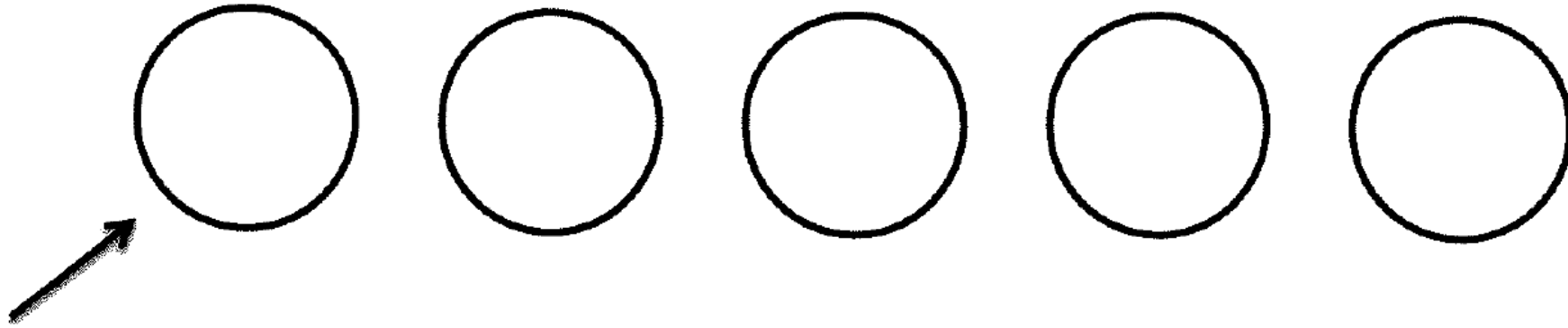
- Nuclear power diminishing above E_c but does not disappear
- Electronic stopping starts before E_c



Modifications to K-P Model

2. Use of realistic cross sections

A simple thought experiment



To the document reader!

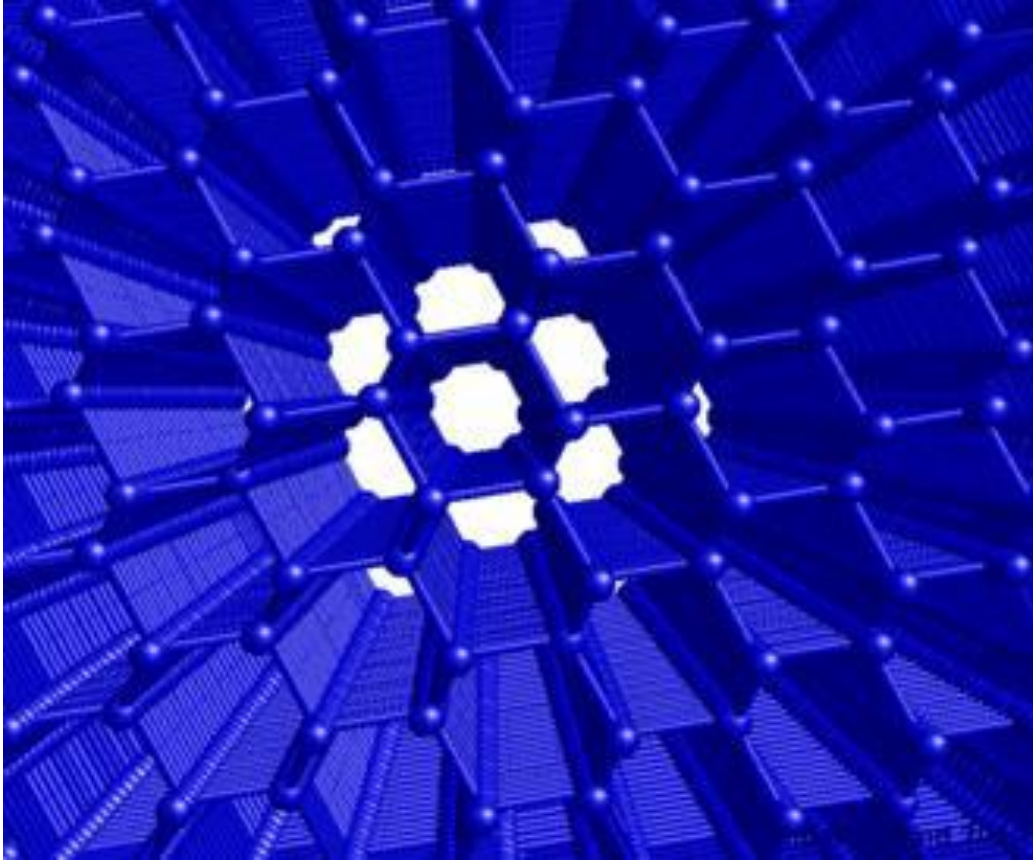
Modifications to K-P Model

3. Effect of crystallinity:

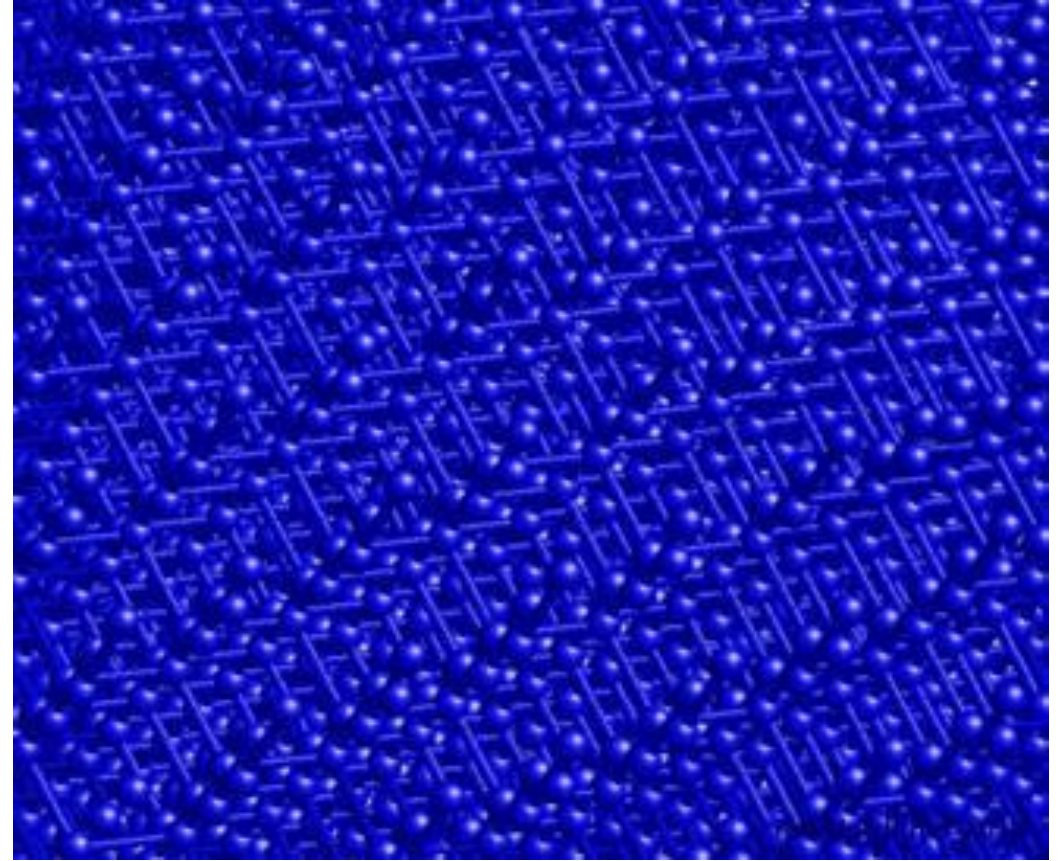
Focusing

Channeling

Channeling



Down a primary zone axis

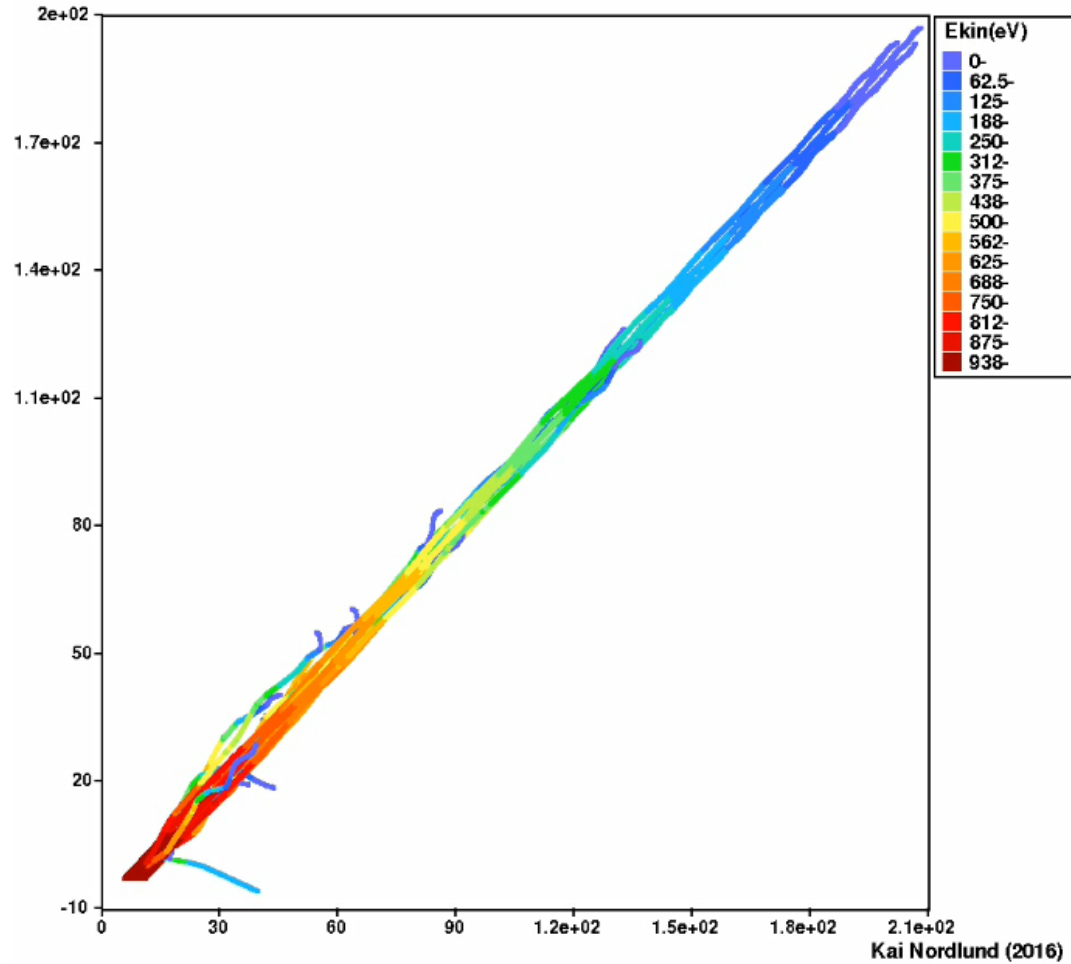


Down a random orientation

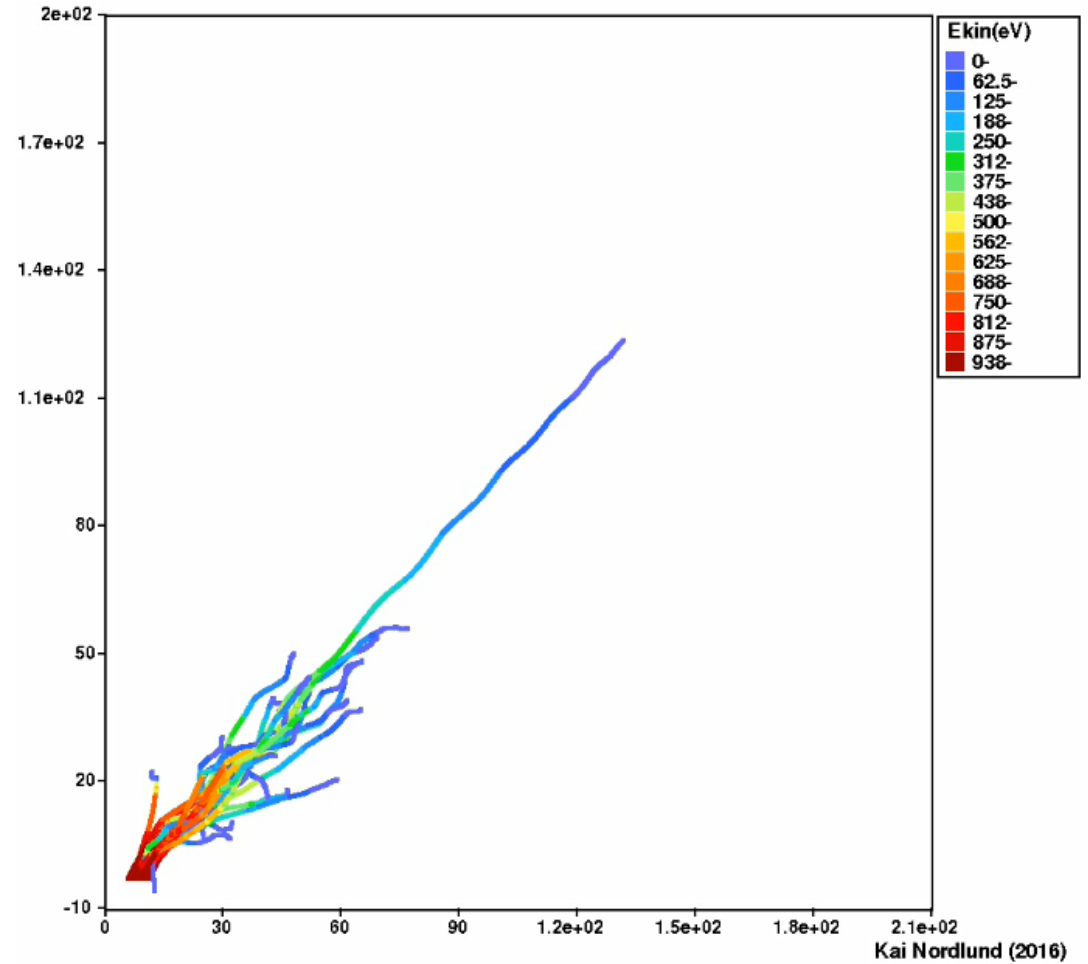
Images from Kai Nordlund

Channeling illustration

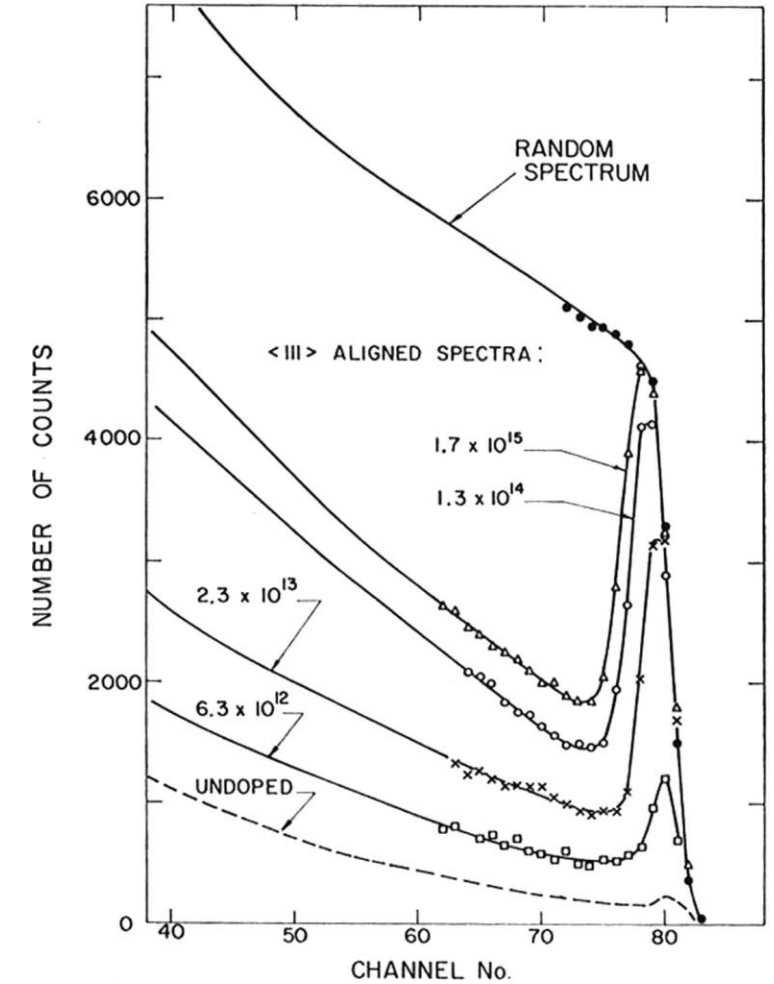
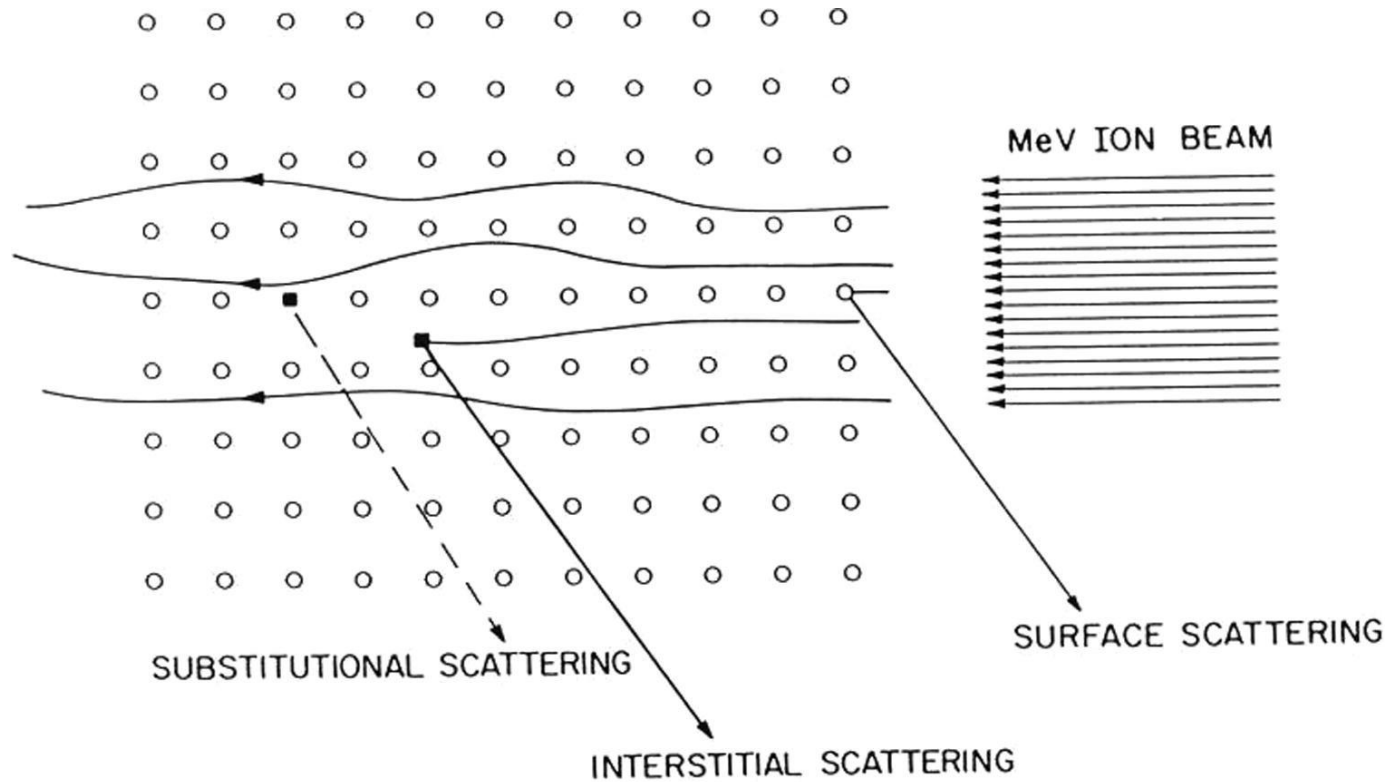
30 individual 1 keV Si in Si ion trajectories, theta=45, phi=0



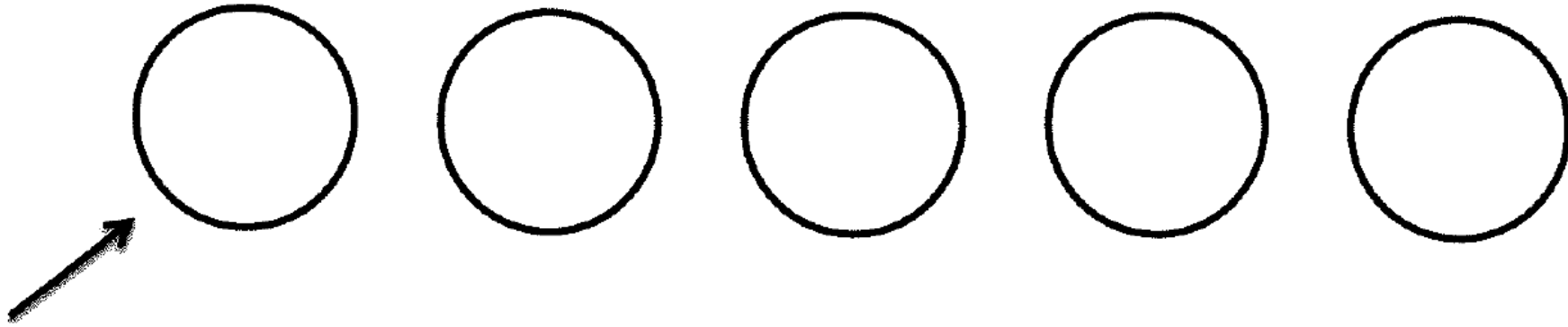
30 individual 1 keV Si in Si ion trajectories, theta=30, phi=0



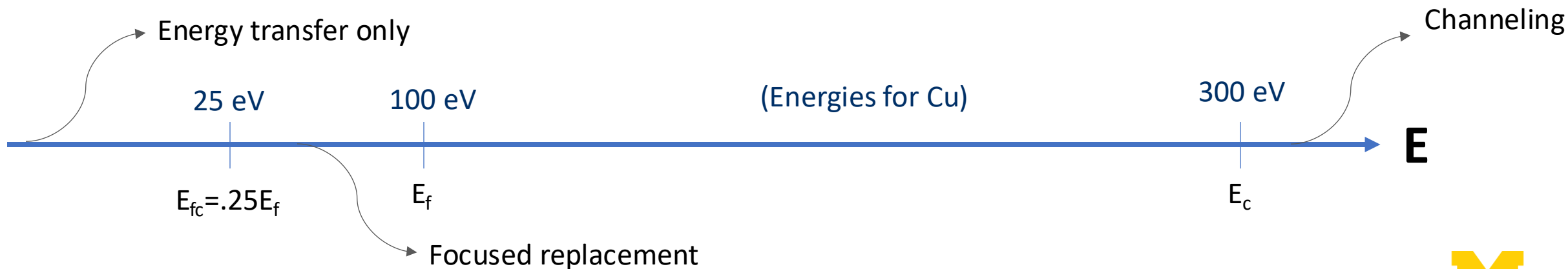
Practical Applications of Channeling



Focusing



- Close-packed energy transfer
- Simplest formalism assumes hard sphere collisions



Coming back to determining $\nu(T)$

<u>Assumption</u>	<u>Correction to $\nu(T)$</u>	<u>Equation in text</u>
#3 – loss of E_d	$0.56 \left(1 + \frac{T}{2E_d} \right)$	(2.31)
#4 – electronic energy loss cut-off	$\xi(T) \left(\frac{T}{2E_d} \right)$	(2.50)
#5 – realistic energy transfer cross-section	$C \frac{T}{2E_d}, 0.52 \leq C \leq 1.22$	(2.33), (2.39)
#6 – crystallinity	$\frac{1-P}{1-2P} \left(\frac{T}{2E_d} \right)^{(1-2P)} - \frac{P}{1-2P}$	(2.104)
	$\sim \left(\frac{T}{2E_d} \right)^{(1-2P)}$	(2.105)

NRT Model

- NRT:

Accounts for Frenkel pair defect efficiency

Used in ASTM E693 to convert neutron flux to dose rate (dpa/s) for steels!!!

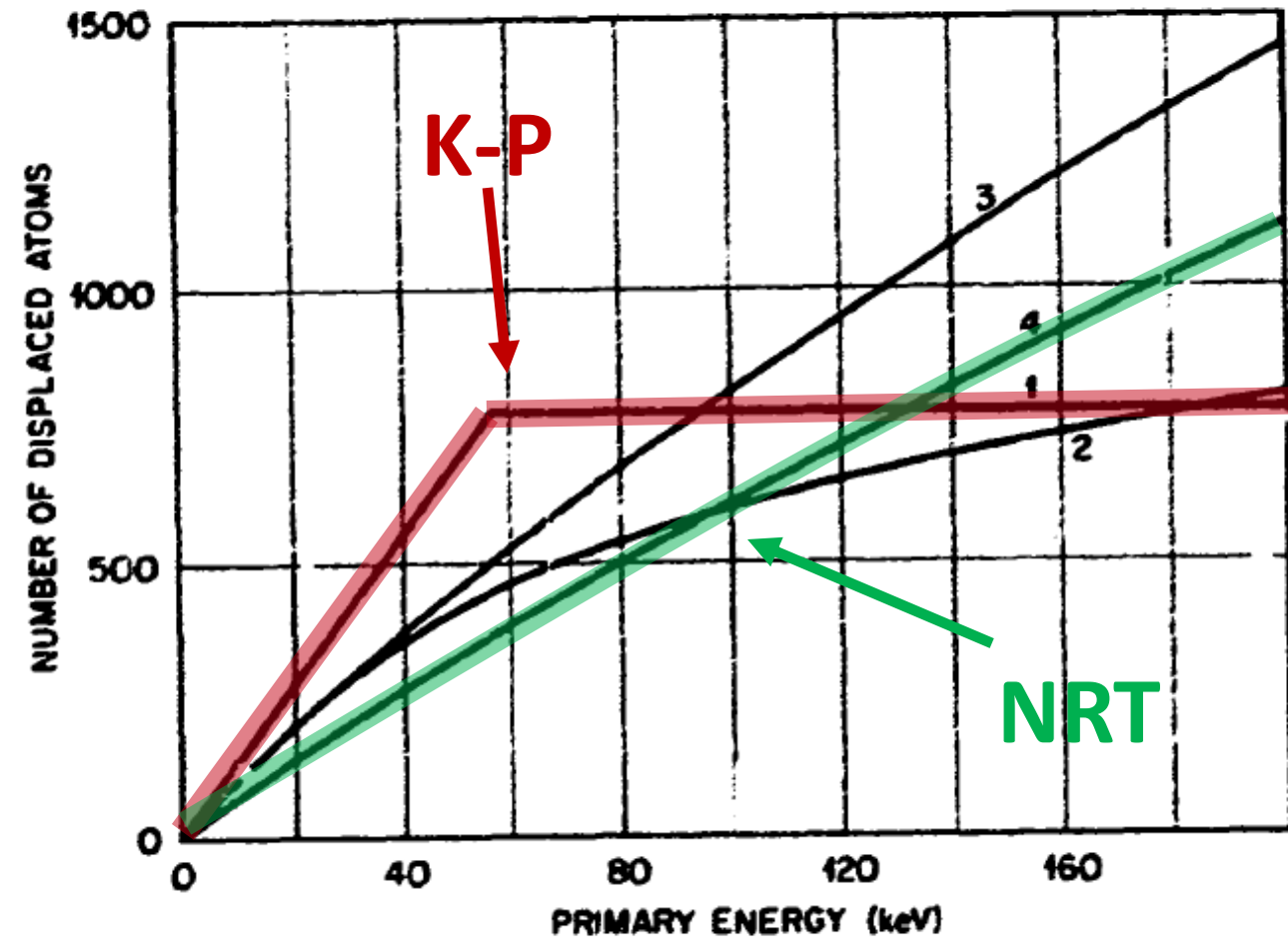


Fig. 2. Comparison of number of displaced atoms generated in bcc iron by a primary knock-on atom. Calculated results correspond to: (1) Kinchin–Pease model with $E_d = 40$ eV and $E_1 = 56$ keV; (2) the half-Nelson formula [4]; (3) earlier computer calculations of Norgett [18], using Torrens–Robinson computer simulation program [11]; and (4) the proposed formula, eqs (5)–(10).

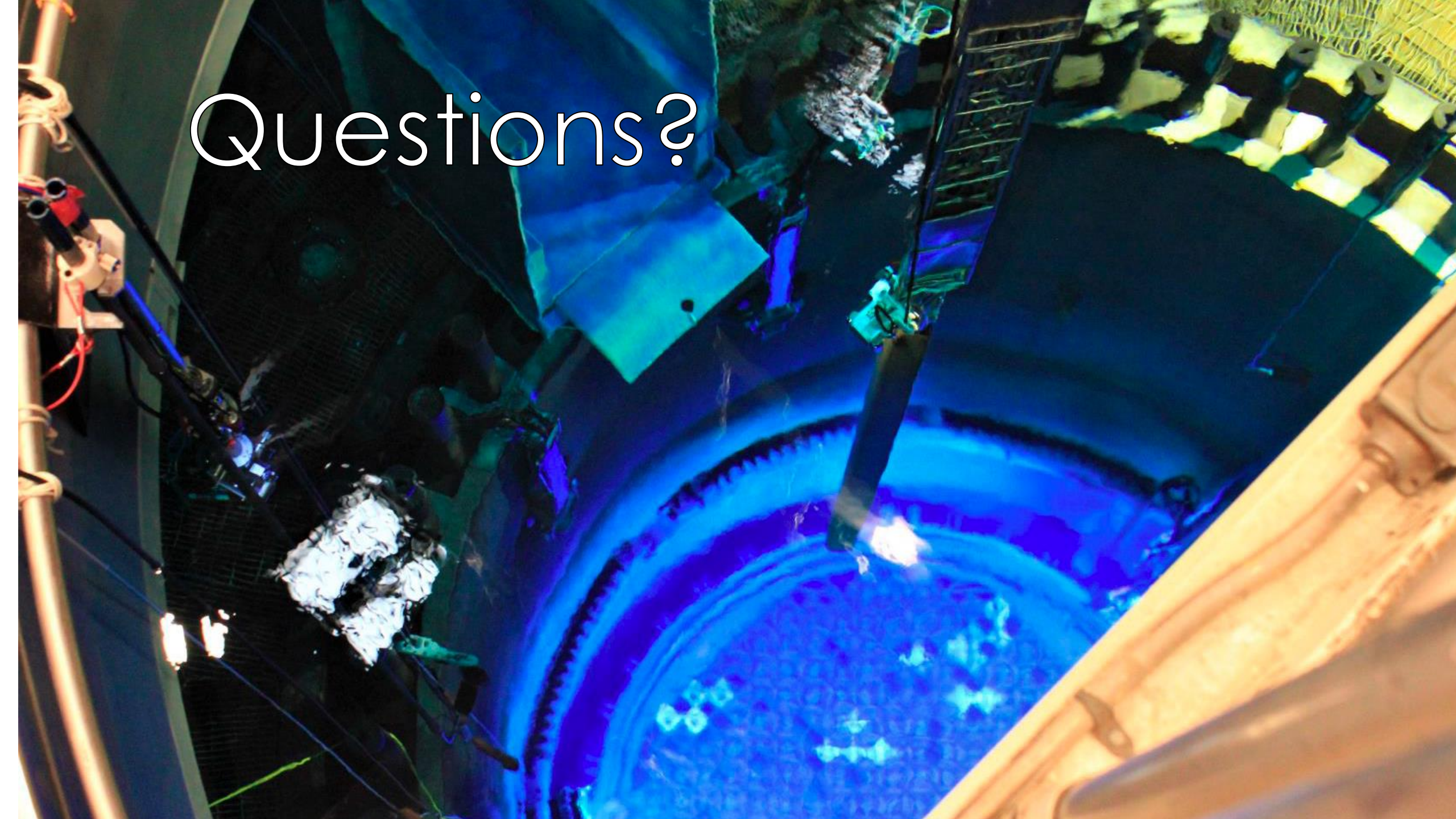
Arc-dpa model

- Over the past 30 years it has become clear that the NRT method for determining dpa in metals is not correct
 - This is due to recombination, which we'll discuss in a few lectures
- To correct the NRT model, the “athermal-recombination corrected dpa”, arc-dpa equation was proposed:

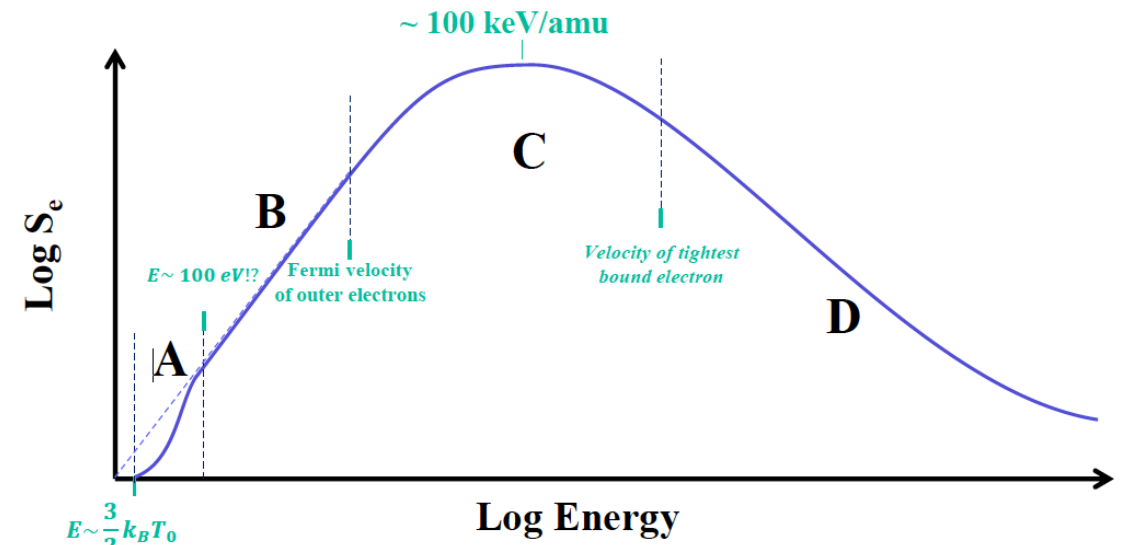
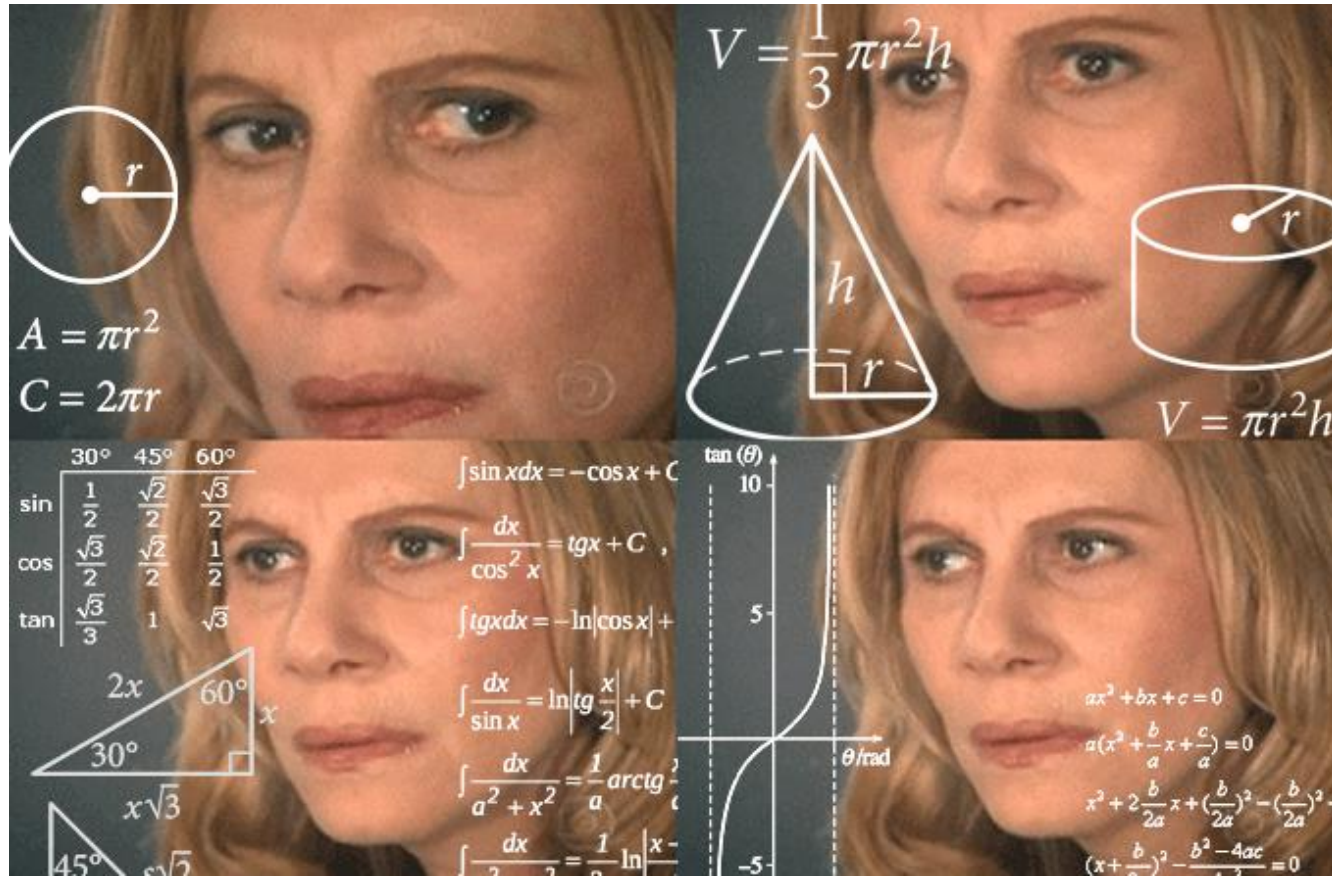
$$N_{d,arcdpa}(T) = \begin{cases} 0 & \text{when } T < E_d \\ 1 & \text{when } E_d < T < 2E_d \\ \frac{0.8 T}{2E_d} \xi(T) & \text{when } 2E_d < T < \infty \end{cases}$$

$$\xi(T) = \frac{1 - c_{arcdpa}}{(2E_d/0.8)^{b_{arcdpa}}} T^{b_{arcdpa}} + c_{arcdpa}$$

Questions?

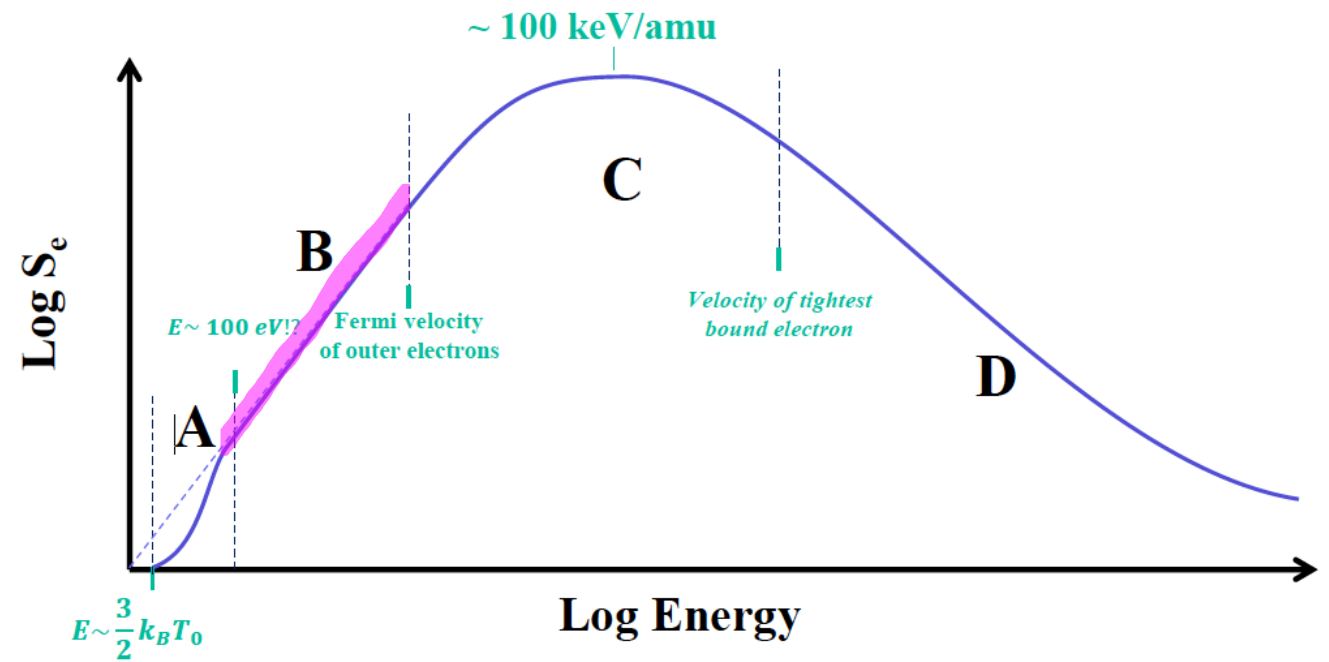


Regime A: low energy regime



The lowest energy regime is the least well known without simple analytical forms

Regime B: LSS theory

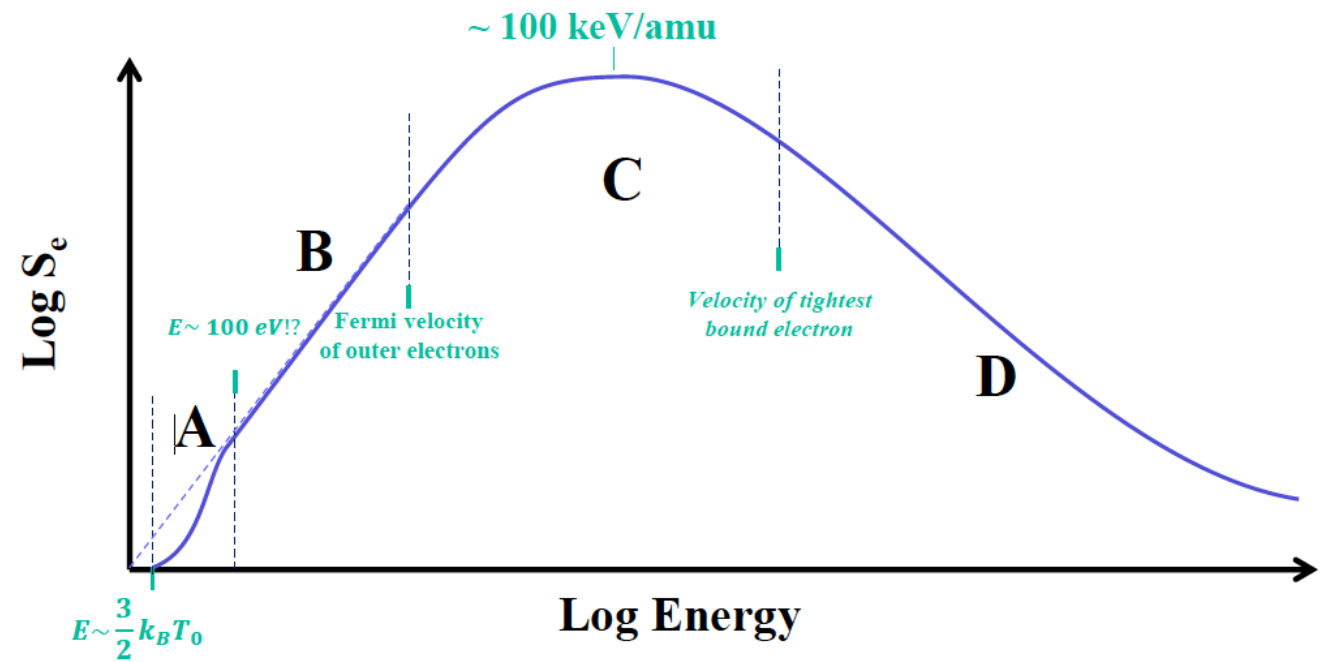
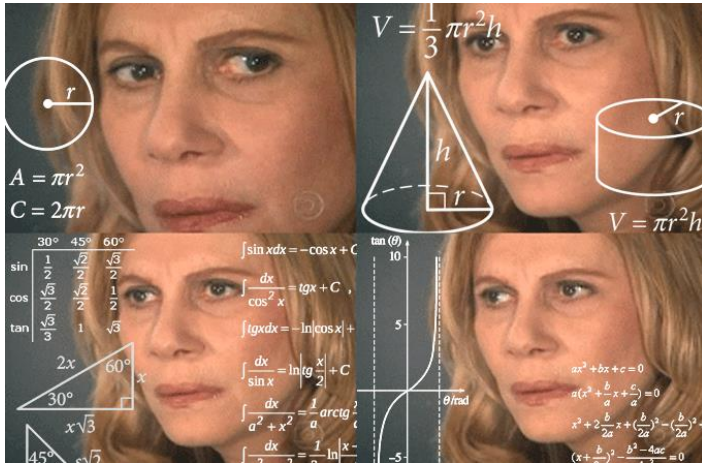


- At higher energies than region A the stopping is almost perfectly linear to the ion velocity,

$$S_e \propto v$$

- This regime has an upper limit at the Fermi velocity of the outermost electron of the material
- Regime and derivations agree well with experiments

Regime C:

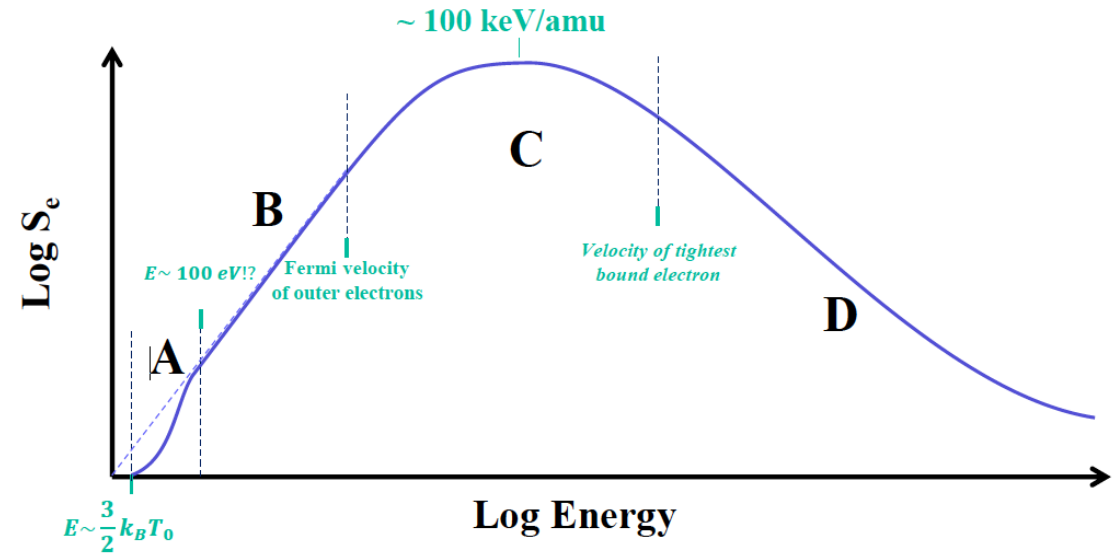


- The maximum region in the stopping power is a regime where the moving ion is partly ionized, and its charge state fluctuates
- I.e. it undergoes stochastic charge exchange processes with the atoms of the material
- There is no simple analytical equation that can describe this region fully reliably



Regimes of D: Bethe-Bloch

- The highest-energy regime can be well understood based on the Bethe-Bloch theory, derived already in the 1930's
- At these high energies, the moving ion is fully or highly charged and does not change charge state
- The Bethe-Bloch equations derive the stopping power quantum mechanically for a charged particle moving in a homogeneous electron gas



$$\left(-\frac{dE}{dx} \right)_e = \frac{N 2\pi Z_1^2 Z_2 \epsilon^4}{E_i} \frac{M}{m_e} \ln \left(\frac{\gamma_e E_i}{\bar{I}} \right) = \frac{2\pi N Z_1^2 M \epsilon^4}{m_e E_i} B \quad B = Z_2 \ln \left(\frac{\gamma_e E_i}{\bar{I}} \right)$$